

ES1A-ES1M

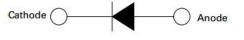
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ES1A-ES1M SURFACE MOUNT SUPER FAST RECTIFIER



Circuit Diagram



Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Overload Drop, High Efficiency
- Low Power Loss
- Super-Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.06 grams(approx)

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic	Symbol	ES1A	ES1B	ES1C	ES1D	ES1E	ES1G	ES1J	ES1K	ES1M	Units
Peak Repetitive Reverse Voltage	V _{RRM}	50	100	150	200	300	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	34	70	105	140	210	280	420	560	700	
Average Rectified Output Current @TL =120°C	lo					1.0					А
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}					30					А
Forward voltage @IF =1.0A	VF		0	.95		1.3		1.7			V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	IR					5 50					μA
Typical junction capacitance (Note 1)	CJ					45.0)				pF
Reverse Recovery Time (Note 2)	Trr					35				75	ns
Electro-Static Discharge	ESD					200	0				V
Typical thermal resistance (Note 3)	R _{θJL}					35					K/W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}				-	55 to +	-150				°C

Note: 1. Measured at 1.0 MHZ and applied reverse voltage of 4.0 V_{DC}

- 2. Measured with I_F=0.5A, I_R=1.0A, I_{\rm fr}=0.25A
- 3. Mounted on P.C. Board with 8.0mm² lead area

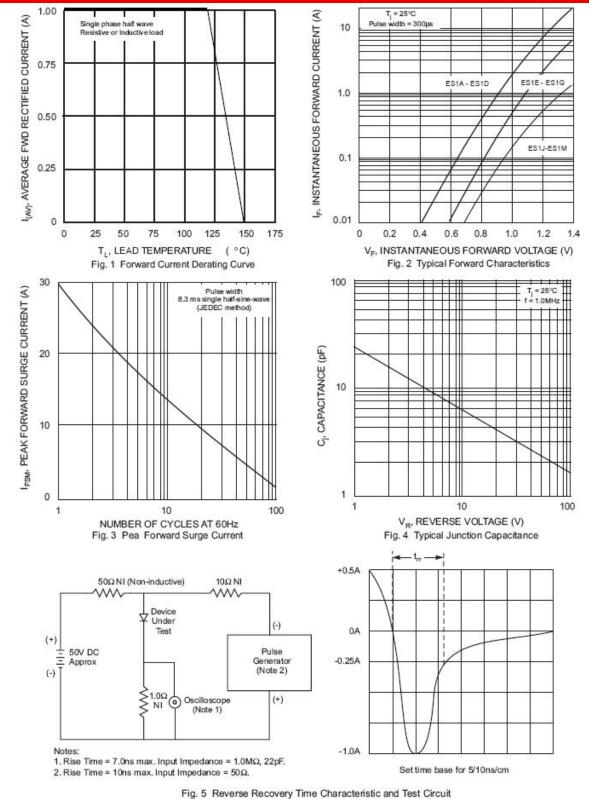
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Ratings and Characteristics Curves

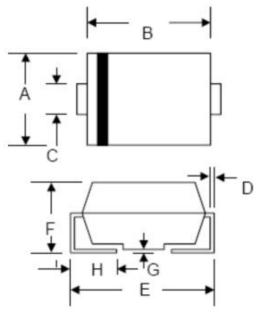


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Mechanical Dimensions SMA



SYMBOL	Milli	meters	Inches			
STMBOL	Min.	Max.	Min.	Max.		
Α	2.40	2.84	0.094	0.112		
В	3.99	4.75	0.157	0.187		
С	1.05	1.70	0.041	0.067		
D	0.15	0.51	0.006	0.020		
E	4.80	5.66	0.189	0.223		
F	1.90	2.95	0.075	0.116		
G	0.05	0.203	0.002	0.008		
н	0.76	1.52	0.030	0.600		

ES

1

A YY

L

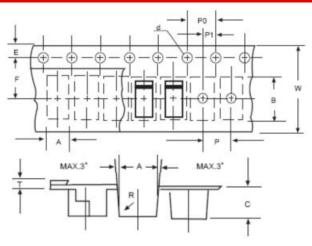
WW

Ordering Information

Device	Package	Shipping			
ES1A-ES1M	SMA (Pb-Free)	5000pcs / reel			

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Carrier Tape Specification SMA



Ы	ES1A	h
	XXXXX	μ

Marking Diagram

Where XXXXX is YYWWL

- = Device Type
- = Forward Current (1A)
- = Reverse Voltage (50V)

= Year = Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

SYMBOL	Millimeters				
STWBOL	Min.	Max.			
Α	2.97	3.17			
В	5.70	5.90			
С	2.32	2.52			
d	1.40	1.60			
E	1.40	1.60			
F	5.60	5.70			
Р	3.90	4.10			
P0	3.90	4.10			
P1	1.90	2.10			
Т	0.25	0.35			
W	11.80	12.20			

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